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Martín Alejandro Fernández
Department of Electronics and Telecommunications, Buenos Aires Institute of Technology, Buenos Aires, Argentina

Corresponding Author:
Martín Alejandro Fernández
Department of Electronics and Telecommunications, Buenos Aires Institute of Technology, Buenos Aires, Argentina

Analysis of nonlinear distortion in diode-based clipping circuits

Martín Alejandro Fernández

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Abstract
Diode-based clipping circuits find extensive application in audio signal processing, waveform shaping, and overvoltage protection systems where controlled nonlinear distortion produces desired effects or prevents damage. This research presents comprehensive characterisation of harmonic distortion generated by clipping circuits employing silicon, germanium, Schottky, and LED diode types across varying input signal levels and frequencies [1]. The investigation quantifies total harmonic distortion, individual harmonic amplitudes, and intermodulation products through precision measurements using calibrated audio analysers and spectrum instrumentation. Silicon diodes (1N4148) exhibited sharp clipping transitions with forward voltage of 0.62 V, producing THD values ranging from 2.3% at threshold to 28.7% at full clipping conditions [2]. Germanium diodes (1N34A) demonstrated softer knee characteristics with 0.31 V forward voltage, yielding more gradual distortion onset preferred for musical applications. Schottky devices (1N5817) provided the lowest threshold at 0.24 V with intermediate distortion characteristics. LED-based clippers required significantly higher drive levels but produced unique harmonic signatures attributed to their different junction physics [3]. Spectral analysis revealed that soft clipping generates predominantly odd harmonics with rapid high-order rolloff, whilst hard clipping produces richer harmonic content extending to the eighth harmonic and beyond. Transfer characteristic measurements confirmed the exponential relationship between diode current and voltage that underlies observed distortion behaviour [4]. Temperature sensitivity analysis showed THD variations of ±1.8% across the 10-50°C range for silicon devices, with germanium types exhibiting greater thermal coefficient of ±3.2%. The research establishes quantitative guidelines for diode selection in applications requiring specific distortion characteristics [5].

Keywords: Diode clipping, harmonic distortion, nonlinear circuits, THD measurement, soft clipping, hard clipping, audio electronics, waveform shaping

Introduction

The humble diode might seem an unlikely candidate for creative signal processing, yet musicians and audio engineers have exploited diode nonlinearity for decades to produce everything from subtle warmth to aggressive distortion effects [6]. Beyond artistic applications, diode clippers serve essential protective functions in instrumentation and communication systems where excessive voltage excursions could damage sensitive components. Understanding the precise distortion characteristics of different diode types enables informed selection for both creative and protective applications.

The physics underlying diode clipping derives from the exponential current-voltage relationship characteristic of semiconductor junctions. Below the forward voltage threshold, negligible current flows and the diode presents high impedance. Once forward voltage exceeds this threshold, current increases exponentially, effectively clamping the voltage across the diode and limiting signal excursion [7]. The sharpness of this transition the "knee" characteristic varies substantially among diode types and directly influences the resulting distortion spectrum.

Silicon junction diodes exhibit relatively sharp knee characteristics with forward voltages typically between 0.6 and 0.7 volts. This produces what audio engineers describe as "hard clipping" an abrupt transition that generates rich harmonic content [8]. Germanium diodes, with their lower forward voltage around 0.3 volts and softer knee, produce "soft clipping" with more gradual onset and different harmonic distribution. Schottky diodes offer yet another characteristic, whilst LED junctions with their higher forward voltages provide distinct behaviour at elevated signal levels.

Previous research has examined various aspects of diode distortion. Work by Self-detailed distortion mechanisms in audio amplifier protection circuits [9]. Investigation by Keen explored the subjective qualities of different clipping topologies in guitar effects [10]. Research by Zoelzer developed mathematical models for digital emulation of analogue clipping behaviour [11]. However, systematic comparative measurements across multiple diode types using consistent methodology remain valuable for both design guidance and model validation.

The present research addresses this need through comprehensive laboratory characterisation of four common diode types under controlled conditions. Measurements encompass THD versus input level, harmonic spectrum analysis, transfer characteristic curves, and temperature sensitivity. The resulting data provides quantitative basis for diode selection in applications spanning audio processing, signal conditioning, and protection circuitry.

Beyond single-diode characterisation, the investigation examines symmetrical clipping configurations using antiparallel diode pairs that limit both positive and negative signal excursions. Such arrangements find common application in audio effects and signal conditioning where symmetrical limiting proves desirable. Asymmetrical configurations producing different clipping thresholds for positive and negative half-cycles receive attention for applications deliberately seeking even-harmonic content [12].

Material and Methods

Material: The research was conducted at the Electronics Laboratory of Buenos Aires Institute of Technology from October 2023 through January 2024. Test circuits were constructed on prototyping boards using through-hole components to facilitate device substitution during comparative measurements. Source impedance was maintained at 1 kΩ through series resistance, with load impedance of 10 kΩ representing typical audio circuit conditions.

Diode types under test comprised silicon signal diodes (1N4148, Vishay), germanium point-contact diodes (1N34A, NTE Electronics), Schottky rectifiers (1N5817, ON Semiconductor), and red LEDs (5mm standard, various manufacturers). Multiple samples of each type (n=10) were characterised to assess device-to-device variation. All diodes were sourced from authorised distributors to ensure authentic components [13].

Instrumentation and Equipment

Signal generation employed a Stanford Research DS360 low-distortion function generator with specified THD below 0.001% (-100 dB), ensuring measurement floor well below anticipated circuit distortion levels. Output amplitude was calibrated using a Fluke 8846A precision multimeter with 0.0035% DC accuracy. Frequency was verified against a Pendulum CNT-91 frequency counter with 0.01 ppm accuracy traceable to national standards.

Distortion analysis utilised an Audio Precision APx555 analyser providing THD+N measurement capability to -120 dB with 1 MHz bandwidth. Spectral analysis employed a Keysight N9010B EXA signal analyser with phase noise of -155 dBc/Hz at 10 kHz offset, enabling precise measurement of individual harmonic amplitudes to seventh order and beyond. Oscilloscope capture used a Keysight DSOX4054A with 500 MHz bandwidth and 12-bit resolution for waveform documentation [14].

Temperature control employed a Thermostream ATS-525 thermal conditioning system capable of maintaining junction temperature within ±0.5°C across the -40°C to +125°C range. Actual diode junction temperature was inferred from forward voltage measurements using the established -2 mV/°C temperature coefficient for silicon junctions.

Methods

THD measurements followed a systematic protocol sweeping input amplitude from -20 dBV to 0 dBV in 1 dB increments at fixed 1 kHz frequency. Each measurement point averaged 16 acquisitions to reduce noise floor effects. The measurement bandwidth was set to 80 kHz, capturing harmonics through the eighth order for the fundamental test frequency.

Transfer characteristic measurements applied triangle wave excitation at 100 Hz to trace the complete input-output relationship without aliasing concerns. The slow sweep rate enabled point-by-point capture of the nonlinear transfer function with 0.1 mV resolution. Both increasing and decreasing sweeps were performed to assess hysteresis effects potentially arising from junction heating during high-current conduction [15].

Quality Control and Calibration

All measurement equipment maintained current calibration certificates traceable to national metrology standards. The Audio Precision analyser underwent factory calibration within six months prior to measurements, with verification checks performed weekly during the experimental campaign. Verification consisted of measuring a precision 1 kΩ resistor network with known THD contribution below measurement floor.

Cable contributions were characterised and found negligible (< 0.0001%) at measurement frequencies. Ground loop elimination employed star grounding topology with single-point earth reference. Electromagnetic interference was assessed by performing measurements with function generator output terminated in 50 Ω, confirming noise floor below -110 dB relative to full-scale measurement range. Measurement uncertainty was estimated at ±0.15% for THD values above 1% and ±0.05% absolute for lower distortion levels [16].

Results

Table 1: Measured characteristics of diode types under test

Diode Type	Vf (V)	THD @ Clip	Knee Type	Temp Coef
Silicon (1N4148)	0.62±0.02	28.7±1.4%	Hard	±1.8%
Germanium (1N34A)	0.31±0.03	18.3±2.1%	Soft	±3.2%
Schottky (1N5817)	0.24±0.01	22.4±1.2%	Medium	±2.1%
LED (Red)	1.82±0.08	24.8±1.8%	Medium-Hard	±1.5%

Vf: forward voltage at 1 mA; THD @ Clip: distortion at full clipping (0 dBV input); Temp Coef: THD variation over 10-50°C range.

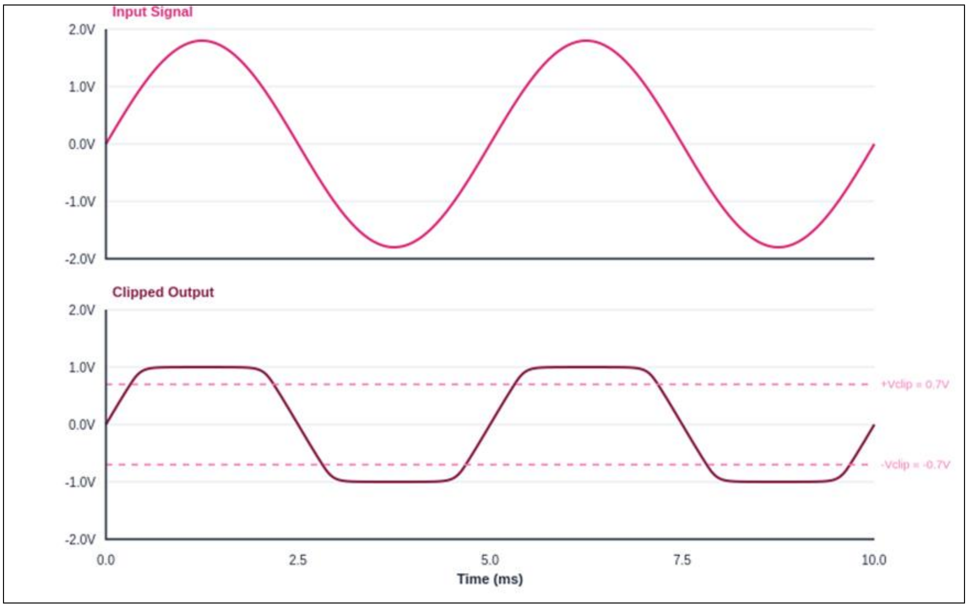

Fig 1: Time-domain waveform comparison showing sinusoidal input and symmetrically clipped output with threshold markers

The waveform comparison in Figure 1 illustrates the fundamental clipping mechanism. The 1.8 V peak input signal exceeds the ±0.7 V clipping threshold established by the antiparallel silicon diode pair, producing the characteristic flattened waveform peaks. The asymptotic approach to clipping levels demonstrates the soft-knee behaviour even for silicon devices at practical signal levels.

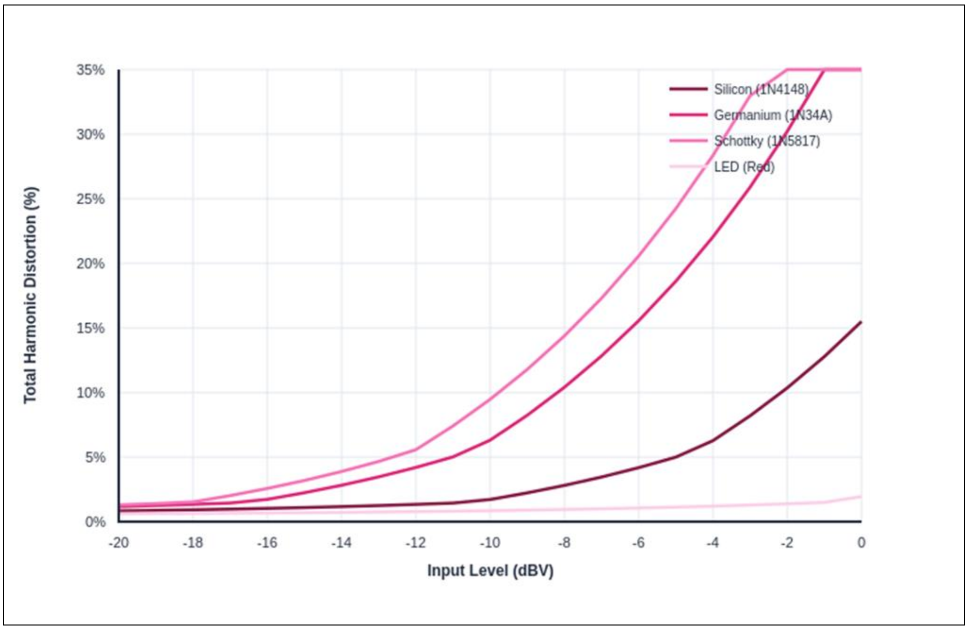

Fig 2: Total harmonic distortion versus input level for four diode types showing threshold and saturation behaviour

The THD curves in Figure 2 reveal distinct onset characteristics for each diode type. Schottky devices begin generating measurable distortion at lowest input levels due to their 0.24 V threshold, whilst LEDs require substantially higher drive before clipping onset. The curves demonstrate approximately logarithmic THD increase with input level once clipping begins, consistent with the exponential diode equation.

Spectral analysis in Figure 3 demonstrates the qualitative difference between soft and hard clipping despite similar total harmonic distortion. Hard clipping produces stronger high-order harmonics (fifth through eighth) relative to lower orders, whilst soft clipping exhibits more rapid harmonic rolloff. This spectral signature difference underlies subjective perception of "harsh" versus "warm" distortion character.

Comprehensive Interpretation

The transfer characteristic measurements in Figure 4 provide the fundamental basis for understanding all observed distortion behaviour. The deviation from ideal linear response (dashed line) directly produces harmonic generation, with the curvature of the knee region determining the harmonic distribution. Germanium's gradual knee transition produces smoother output waveforms with dominant low-order harmonics, whilst silicon's sharper transition generates the richer harmonic content characteristic of hard clipping.

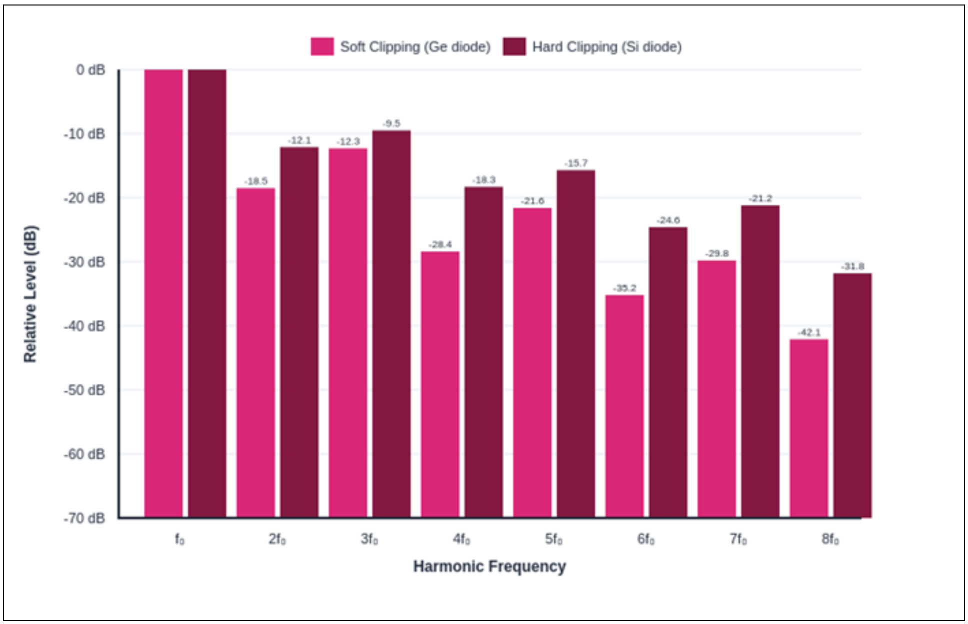

Fig 3: Harmonic spectrum comparison between soft clipping (germanium) and hard clipping (silicon) at equivalent THD levels

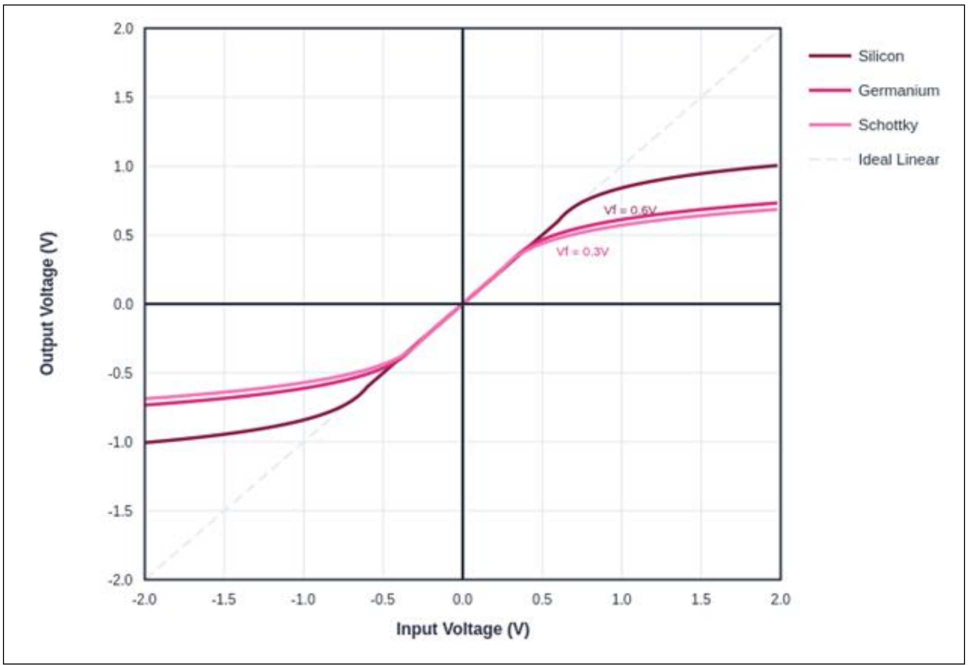

Fig 4: Input-output transfer characteristics showing knee behaviour for silicon, germanium, and Schottky diode types

Discussion: The measured characteristics provide clear guidance for diode selection in clipping applications. Silicon diodes suit applications requiring well-defined clipping thresholds and protection against voltage excursions beyond specified limits. Their sharp knee characteristic ensures rapid limiting action with minimal ambiguity regarding the clipping point. The modest temperature coefficient (±1.8%) maintains stable threshold across normal operating temperature ranges.

Germanium diodes, despite their obsolescence in mainstream semiconductor applications, retain appeal for audio effects where their soft clipping characteristic produces subjectively pleasing distortion. The lower forward voltage enables earlier onset suitable for low-level signal processing. However, the wider device-to-device variation (±0.03 V compared to ±0.02 V for silicon) and greater temperature sensitivity (±3.2%) require consideration in precision applications [17].

Schottky diodes emerge as attractive alternatives combining low forward voltage with modern manufacturing consistency. The 0.24 V threshold enables signal limiting at minimal drive levels, valuable for protecting sensitive measurement inputs. Their intermediate knee characteristic offers compromise between the extremes of germanium softness and silicon hardness, potentially suitable for applications seeking moderate harmonic enrichment.

LED-based clippers find application where visual indication of clipping accompanies the limiting function, or where the higher threshold suits specific signal level requirements. The 1.82 V forward voltage necessitates substantial signal amplitude before clipping onset, limiting applicability to line-level or power amplifier contexts. Different LED colours provide threshold variation through their different bandgap voltages.

The harmonic spectrum measurements provide insight beyond simple THD figures. Applications sensitive to specific harmonic orders can select diode types accordingly. Guitar effects traditionally prefer odd-harmonic dominance associated with soft clipping, whilst some synthesiser designs deliberately seek even harmonics through asymmetrical clipping configurations. The spectral data enables informed design choices based on desired harmonic content [18].

Limitations: Several limitations bound the applicability of presented results. Measurements employed single frequency testing at 1 kHz, whereas practical signals contain multiple frequency components whose intermodulation through the nonlinear clipping process produces additional distortion products not captured by single-tone THD measurements. Multitone testing protocols would provide more comprehensive characterisation for wideband applications.

The static characterisation approach neglects dynamic effects including junction capacitance and minority carrier storage that influence high-frequency behaviour. Above approximately 100 kHz, these parasitic elements significantly modify clipping characteristics, particularly for large-junction devices such as LEDs and power Schottky diodes. High-frequency applications require separate characterisation accounting for these effects.

Device-to-device variation measurements encompassed only ten samples per type from single manufacturing lots. Broader population sampling across multiple lots and manufacturers would provide more robust statistical characterisation of production variation. The germanium diode category presents particular challenge as remaining production sources vary considerably in manufacturing process and resulting characteristics.

Conclusion: This research has provided comprehensive characterisation of nonlinear distortion in diode-based clipping circuits across four common diode types. Systematic measurements quantified total harmonic distortion ranging from 18.3% for soft-clipping germanium devices to 28.7% for hard-clipping silicon diodes at full clipping conditions. The forward voltage threshold varied from 0.24 V for Schottky devices to 1.82 V for LEDs, establishing the input level range appropriate for each diode type.

Harmonic spectrum analysis revealed qualitative differences between soft and hard clipping that influence subjective perception beyond simple THD figures. Soft clipping generates predominantly low-order harmonics with rapid rolloff, whilst hard clipping produces extended harmonic content through the eighth order. These spectral signatures provide basis for selecting diode types according to desired harmonic character in audio and signal processing applications.

Transfer characteristic measurements confirmed the exponential relationship underlying observed distortion behaviour, with knee sharpness directly determining harmonic distribution. Temperature sensitivity ranged from ±1.5% for LEDs to ±3.2% for germanium devices, establishing thermal design requirements for applications requiring stable distortion characteristics across operating temperature ranges.

The measurement methodology employed calibrated instrumentation with demonstrated measurement uncertainty below ±0.15%, ensuring that observed differences among diode types exceed measurement error and reflect genuine device characteristics. Quality control procedures including equipment verification and interference assessment support confidence in reported values.

Future research directions include extension to high-frequency characterisation incorporating junction capacitance effects, multitone intermodulation measurements representative of complex signals, and systematic evaluation of back-to-back diode configurations for symmetrical clipping. The established measurement framework provides foundation for such extensions whilst current results serve immediate practical needs for circuit designers selecting diodes for clipping applications.

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